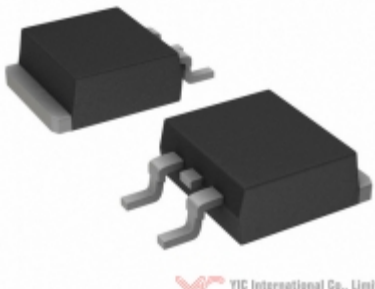









	<h2 style="color: red;">FQB5N60CTM</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">FQB5N60CTM</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 600V 4.5A D2PAK
<p>Image may be representation. See specs for product details.</p>	<b>Datenblätter:</b>	 <a href="#">FQB5N60CTM.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 918 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS

### Spezifikationen

Teilenummer	<a href="#">FQB5N60CTM</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 600V 4.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	918 pcs Stock
detaillierte Beschreibung	N-Channel 600V 4.5A (Tc) 3.13W (Ta), 100W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 100W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	2.5 Ohm @ 2.25A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	670pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQB5N60CTM ist neu im Original, Suche FQB5N60CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB5N60CTM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB5N60CTM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB5N50TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 4.5A D2PAK</p>	 <p><b>FQB5N50CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 5A A.D2PAK</p>	 <p><b>FQB5N60</b> FSC FQB5N60 FSC</p>	 <p><b>FQB5N60CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 4.5A D2PAK</p>
 <p><b>FQB5N50TM</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 4.5A D2PAK</p>	 <p><b>FQB5N60CTM_WS</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 4.5A</p>	 <p><b>FQB5N60TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 5A D2PAK</p>	 <p><b>FQB5N60TM</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 5A D2PAK</p>

### heiße Teile

Mehr

FQB4N90TM	FQB4P25TM	FQB4P25TM	FQB5N03	FQB5N06
FQB5N06C	FQB5N06L	FQB5N06LTM	FQB5N06LTM	FQB5N06M
FQB5N06TM	FQB5N06TM	FQB5N06TM-NL	FQB5N06TM	FQB5N06TM
FQB5N10	FQB5N10TM	FQB5N10TM	FQB5N20L	FQB5N30TM
FQB5N30TM	FQB5N50C	FQB5N50CF	FQB5N50CTM	FQB5N50CTM
FQB5N60CTM	FQB5N90TM	FQB5N90TM	FQB5P10TM	FQB5P10TM
FQB630TM	FQB630TM	FQB65N06	FQB65N06TM	FQB65N06TM
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FQB6N50TM	FQB6N60C	FQB6N60CTM	FQB6N60CTM	FQB6N60TM
FQB6N60TM	FQB6N70TM	FQB6N70TM	FQB6N90TM	FQB6N90TM_AM002

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

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